10.3Gb/s XFP Transceiver

APX55HM0xDL80

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ATOP's APX55HM0xDL80 Small Form Factor 10Gb/s XFP transceivers are compatible with XFP MSA Specification. They comply with SONET OC-192 IR-2,OC-192 IR-3,SDH STM S-64.2b, STM S-64.3b as well as with 10G Ethernet 10G BASE-ER/EW per IEEE802.3ae and 80km 10G Fibre Channel applications.

Product Features

- ✓ Supports 9.95 to 11.3Gb/s
- ✓ Duplex LC connector
- ✓ Hot-pluggable XFP footprint
- ✓ Cooled 1550nm EML laser
- ✓ RoHS compliant and Lead Free
- ✓ 80Km link length
- ✓ Metal enclosure for lower EMI
- ✓ Built-in dual CDR
- ✓ +5.0V and +3.3V power supply and power dissipation <2.5W
- ✓ XFP MSA INF-8077I Compliant
- ✓ XFI loop-back Support

Applications

- ✓ SONET OC-192 IR-2/IR-3
  SDH STM S-64.2b/S-64.3b
  ITU-T G.709
- ✓ IEEE 802.3ae 10GBASE-ZR/
  ZW 80km 10G Ethernet
- ✓ Supports OTN/1TU-T G.709

Product Selection

Part Number	Operating Case temperature	DDMI
APX55HM0CDL80	Commercial(0~70℃)	Yes
APX55HM0EDL80	Extend(0~85℃)	Yes
APX55HM0IDL80	Industrial(-40~85℃)	Yes

ATOP Corporation
Tel: +86 755 86674946
sales@atoptechnology.com
atoptechnology.com

Regulatory Compliance

- ESD to the Electrical PINs: compatible with MIL-STD-883 Method 3015
- ESD to the Duplex LC Receptacle: compatible with IEC 61000-4-2
- Immunity compatible with IEC 61000-4-3
- EMI compatible with FCC Part 15 Class B EN55022 Class B (CISPR 22B) VCCI Class B
- Laser Eye Safety compatible with FDA 21CFR 1040.10 and 1040.11 EN60950, EN (IEC) 60825-1,2
- RoHS compliant with RoHS 2 (2011/65/EU)

Pin Descriptions

Pin	Symbol	Name	Ref.
1	GND	Module Ground	
2	VEE5	Optional-5.2 Power Supply-not required	
3	MOD_DESEL	Module De-select; When held low allows the module to respond to 2-wire serial interface. LVTTL-I	
4	/INTERRUPT	Interrupt; Indicates presence of an important condition which can be read via the 2-wire serial interface. LVTTL-O	2
5	TX_DIS	Transmitter Disable. Logic1 indicates laser output disabled, LVTTL-I	
6	VCC5	+5V Power Supply	
7	GND	Module Ground	1
8	VCC3	+3.3V Power Supply	
9	VCC3	+3.3V Power Supply	
10	SCL	2-Wire Serial Interface Clock. LVTTL-I	2
11	SDA	2-Wire Serial Interface Data Line. LVTTL-I/O	2
12	MOD_ Abs	Indicates Module is not present. Grounded in the Module. LVTTL-O	2
13	MOD_NR	Module Not Ready; Indicating Module Operational Fault. Open-collector. LVTTL-O	2
14	RX_LOS	Loss of Signal indication. Logic 1 indicates loss of Signal. Open-collector. LVTTL-O	2
15	GND	Module Ground	1
16	GND	Module Ground	1
17	RD-	Receiver Inverted Data Output. CML-O	
18	RD+	Receiver Non-Inverted Data Output. CML-O	
19	GND	Module Ground	1
20	VCC2	+1.8V Power Supply (Not required).	3
21	P_DOWN/RST	Power down; When high, requires the module to limit power consumption to 1.5W or below. 2-Wire serial interface must be functional in the low power mode. LVTTL-I Reset; The falling edge initiates a complete reset of the module including the 2-wire serial interface, equivalent to a power cycle. LVTTL-I	

22	VCC2	+1.8V Power Supply (Not required)	3
23	GND	Module Ground	1
24	REFCLK+	Reference Clock (Not required)	
25	REFCLK-	Reference Clock (Not required)	
26	GND	Module Ground	1
27	GND	Module Ground	1
28	TD-	Transmitter Inverted Data Input. CML-I	
29	TD+	Transmitter Non-Inverted Data Input. CML-I	
30	GND	Module Ground	1

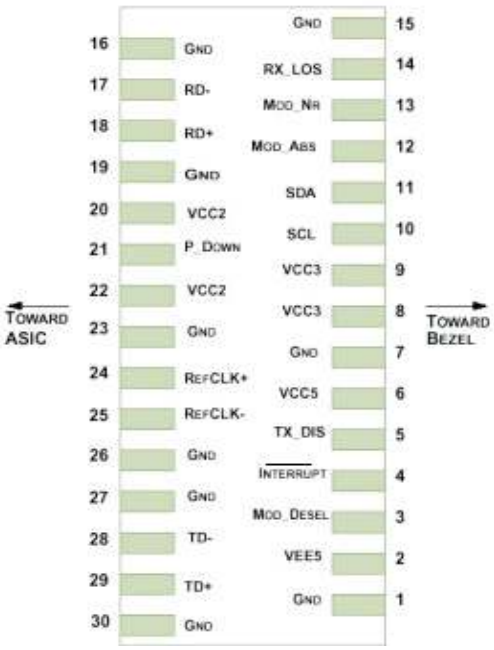
Notes:

1.Module ground pins GND are isolated from the module case and chassis ground within the module.

2.Open collector, Should be pulled up with 4.7K-10Kohms to a voltage between 3.15V and 3.6V on the host board.

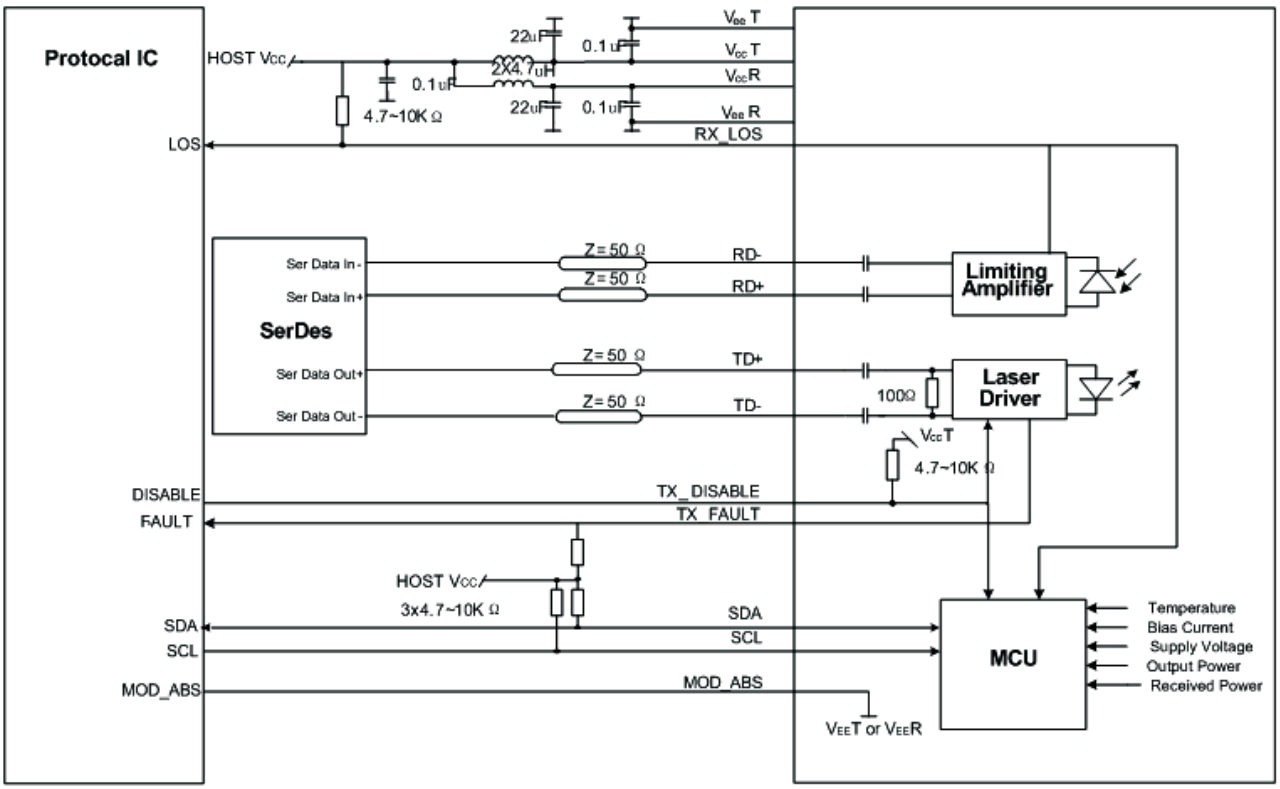
3.The pins are open within module.

Pin-out Connector Block on Host Board



Pin-out of Connector Block on Host Board

Recommend Circuit Schematic



Absolute Maximum Ratings

Parameter	Symbol	Min	Typ	Max	Unit	Ref.
Maximum Supply Voltage	Vcc3	-0.5		+4.0	V	
	Vcc5	-0.5		+6.0	V	
Storage Temperature	TS	-40		+85	°C	
Operating Humidity	RH	0		85	%	

Recommended Operating Conditions

Parameter	Symbol	Min	Typ	Max	Unit	Ref.
Power Supply Voltage	Vcc3	3.13	3.30	3.47	V	
	Vcc5	4.75	5.0	5.25	V	
Power Supply Current	Icc3			600	mA	
	Icc5			100	mA	
Case Operating Temperature	Tc	0		+70	°C	Commercial
	Te	0		+85		Extend
	TI	-40		+85		Industrial
Bit Rate	Br	9.95		11.3	Gbps	
9/125um G.652 SMF	Lmax			80	km	

Electrical Characteristics (TOP=25°C, Vcc=3.3Volts)

Parameter	Symbol	Min	Typ	Max	Unit	Ref.
Transmitter						
Input differential impedance	Rin	80	100	120	Ω	1
Differential data input swing	Vin, pp	120		850	mV	
TX Disable-High		Vcc – 0.8		Vcc	V	
TX Disable-Low		Vee		Vee+ 0.8	V	
TX Fault-High		Vcc-0.8		Vcc	V	
TX Fault-Low		Vee		Vee+0.8	V	
Receiver						
Differential data output swing	Vout, pp	300		850	mV	2
Data output rise time	Tr	30			ps	3
Data output fall time	Tf	30			ps	3
LOS-High		Vcc – 0.8		Vcc	V	
LOS-Low		Vee		Vee+0.8	V	

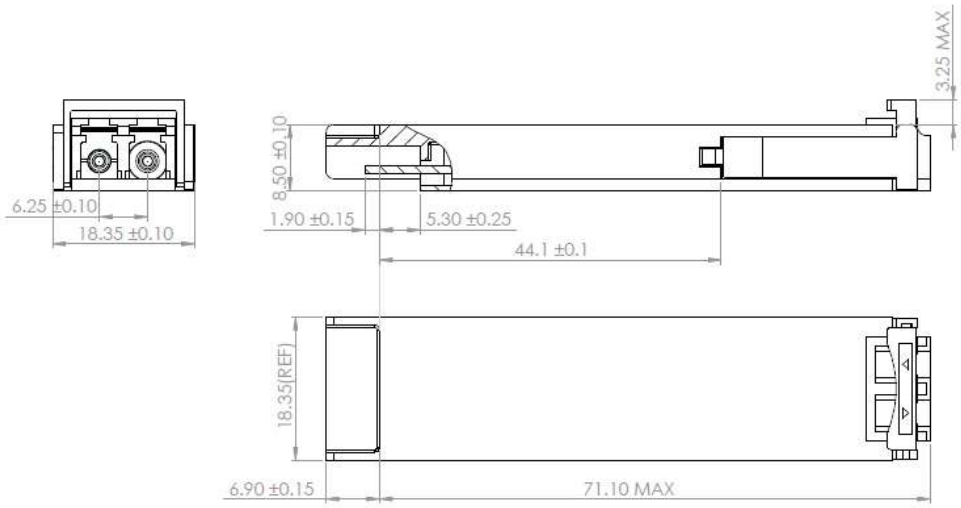
Notes:
1. AC coupled.
2. Into 100 ohm differential termination.
3. 20 – 80 %

Optical Characteristics (TOP=25°C, Vcc=3.3 Volts)

Parameter	Symbol	Min	Typ	Max	Unit	Ref.
Transmitter						
Output Opt. Power	PO	0		4	dBm	
Optical Wavelength	λ	1530		1565	nm	
Side-Mode Suppression Ratio	SMSR	30			dB	
RMS Spectral Width(-20dB)	σ			1	nm	
Optical Extinction Ratio	ER	9.0			dB	
Tx Jitter(SONET)20KHZ-80MHZ	Txj1			0.3	UI	3
Tx Jitter(SONET)4MHZ-80MHZ	TXj2			0.1	UI	3
Path penalty at 1600ps/nm@9.95Gb/s				3	dB	
Relative Intensity Noise	RIN			-128	dB/Hz	
Receiver						
RX Sensitivity @10.3Gb/s	SENS			-24	dBm	1,2
Receiver Overload		-7			dBm	
Optical Center Wavelength	λC	1260		1600	nm	
LOS De-Assert	LOSD			-28	dBm	
LOS Assert	LOSA	-37			dBm	
LOS Hysteresis		0.5			dB	

Notes:
1.Measured with conformance signals defined in FC-PI-2 Rev. 10.0 specifications.
2.Measured with PRBS 2^{31}-1 at 10^{-12} BER.
3.GR-253-CORE Issue 4.

Mechanical Specifications



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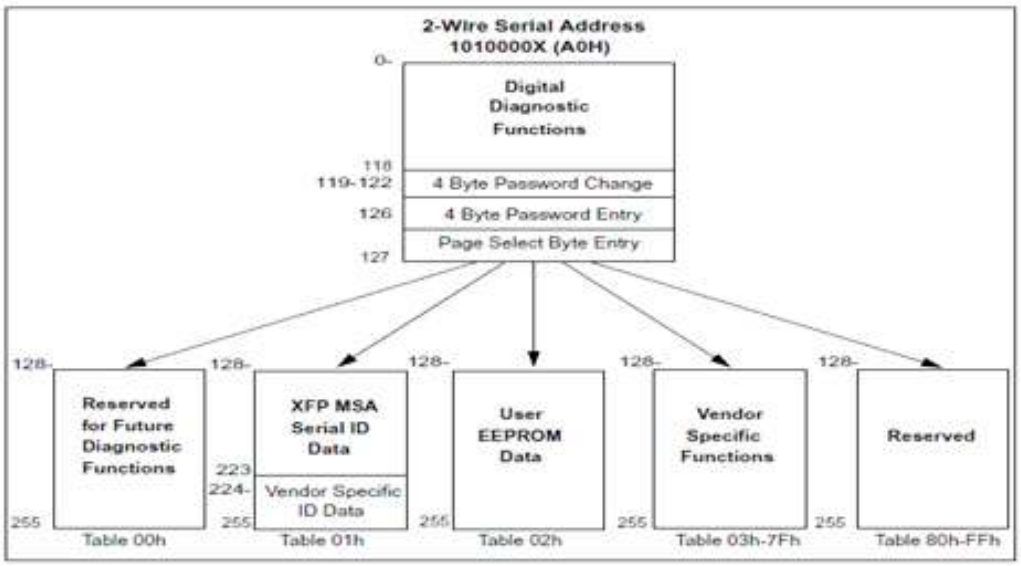
EEPROM Information

• EEPROM memory map specific data field description is as below:



Digital Diagnostic Monitoring Interface

Parameter	Range	Accuracy	Calibration
Temperature	0 to +70°C (C) 0 to +85°C (E) -40 to +85°C (I)	±3°C	Internal
Voltage	2.97 to 3.63V	±3%	Internal
Bias Current	0 to 100mA	±10%	Internal
TX Power	0 to 4dBm	±3dB	Internal
RX Power	-24 to -7dBm	±3dB	Internal

Five transceiver parameter values are monitored. The following table defines the monitored parameter's accuracy.

Revision History

Revision	Initiated	Reviewed	Approved	DCN	Release Date
Version1.0	Xiaoaiyou	Sunbing	Wanggang	New Released.	July 28, 2016

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